

# Wei Niu

## List of Publications by Year in descending order

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41  
papers

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567281

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454955

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all docs

41  
docs citations

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times ranked

1454  
citing authors

#	ARTICLE	IF	CITATIONS
1	Fully Optical Modulation of the Two-Dimensional Electron Gas at the $\text{I}^3\text{-Al}_2\text{O}_3/\text{SrTiO}_3$ Interface. <i>Journal of Physical Chemistry Letters</i> , 2022, 13, 2976-2985.	4.6	9
2	Self-Induced Intercalation Tunable Interlayer Exchange Coupling in a Synthetic van der Waals Antiferromagnet. <i>Advanced Functional Materials</i> , 2022, 32, .	14.9	10
3	Charge-Transfer-Induced Multivalent States with Resultant Emergent Magnetism in Transition-Metal Oxide Heterostructures. <i>Advanced Electronic Materials</i> , 2021, 7, .	5.1	5
4	Recent Advances on Spin-Polarized Two-Dimensional Electron Gases at Oxide Interfaces. <i>ACS Applied Electronic Materials</i> , 2021, 3, 128-144.	4.3	11
5	Room-temperature intrinsic ferromagnetism in epitaxial $\text{CrTe}_2$ ultrathin films. <i>Nature Communications</i> , 2021, 12, 2492.	12.8	179
6	Ferroelectric control of a spin-polarized two-dimensional electron gas. <i>Physical Review B</i> , 2021, 103, .	3.2	8
7	Giant Topological Hall Effect in van der Waals Heterostructures of $\text{CrTe}_2/\text{Bi}_2\text{Te}_3$ . <i>ACS Nano</i> , 2021, 15, 15710-15719.	14.6	34
8	Antisymmetric magnetoresistance in $\text{Fe}/\text{GeTe}$ nanodevices of inhomogeneous thickness. <i>Physical Review B</i> , 2021, 104, .	3.2	16
9	Probing the atomic-scale ferromagnetism in van der Waals magnet $\text{CrSiTe}_3$ . <i>Applied Physics Letters</i> , 2021, 119, .	3.3	12
10	Large Linear Magnetoresistance of High-Mobility 2D Electron System at Nonisostructural $\text{I}^3\text{-Al}_2\text{O}_3/\text{SrTiO}_3$ Heterointerfaces. <i>Advanced Materials Interfaces</i> , 2021, 8, 2101235.	3.7	12
11	Realizing Wafer-Scale and Low-Voltage Operation $\text{MoS}_2$ Transistors via Electrolyte Gating. <i>Advanced Electronic Materials</i> , 2020, 6, 1900838.	5.1	15
12	The Role of the Height Fluctuation Effect in the Tunable Interfacial Electronic Structure of the Vertically Stacked $\text{BP}/\text{MoS}_2$ Heterojunction. <i>Journal of Physical Chemistry C</i> , 2020, 124, 20256-20261.	3.1	4
13	Electrolyte gate controlled metal-insulator transitions of the $\text{CaZrO}_3/\text{SrTiO}_3$ heterointerface. <i>Applied Physics Letters</i> , 2019, 115, 061601.	3.3	14
14	Monolayer Modification of $\text{VTe}_2$ and Its Charge Density Wave. <i>Journal of Physical Chemistry Letters</i> , 2019, 10, 4987-4993.	4.6	43
15	Strain-driven lattice distortion and the resultant magnetic properties of $\text{La}_{0.7}\text{Sr}_{0.3}\text{MnO}_3/\text{BaTiO}_3$ superlattices. <i>Applied Physics Letters</i> , 2019, 115, 201604.	3.3	4
16	Stimulating Oxide Heterostructures: A Review on Controlling $\text{SrTiO}_3$ -Based Heterointerfaces with External Stimuli. <i>Advanced Materials Interfaces</i> , 2019, 6, 1900772.	3.7	56
17	Ultrafast Orbital-Oriented Control of Magnetization in Half-Metallic $\text{La}_{0.7}\text{Sr}_{0.3}\text{MnO}_3$ Films. <i>Advanced Materials</i> , 2019, 31, e1806443.	21.0	13
18	Observation of Small Polaron and Acoustic Phonon Coupling in Ultrathin $\text{La}_{0.7}\text{Sr}_{0.3}\text{MnO}_3/\text{SrTiO}_3$ Structures. <i>Physica Status Solidi - Rapid Research Letters</i> , 2019, 13, 1800657.	2.4	2

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19	Oxide Interfaces: Diluted Oxide Interfaces with Tunable Ground States (Adv. Mater. 10/2019). Advanced Materials, 2019, 31, 1970072.	21.0	3
20	Diluted Oxide Interfaces with Tunable Ground States. Advanced Materials, 2019, 31, e1805970.	21.0	28
21	Topological Phase Transition-Induced Triaxial Vector Magnetoresistance in $(\text{Bi}_{1-x}\text{In}_x)_2\text{Se}_3$ Nanodevices. ACS Nano, 2018, 12, 1537-1543.	14.6	13
22	Direct Demonstration of the Emergent Magnetism Resulting from the Multivalence Mn in a $\text{LaMnO}_3$ Epitaxial Thin Film System. Advanced Electronic Materials, 2018, 4, 1800055.	5.1	27
23	Transport evidence of 3D topological nodal-line semimetal phase in $\text{ZrSiS}$ . Frontiers of Physics, 2018, 13, 1.	5.0	30
24	Tuning the Two-Dimensional Electron Gas at Oxide Interfaces with $\text{Ti}^{\text{O}}$ Configurations: Evidence from X-ray Photoelectron Spectroscopy. ACS Applied Materials & Interfaces, 2018, 10, 1434-1439.	8.0	15
25	The atomic-scale magnetism of $\text{Co}_2\text{FeAl}$ Heusler alloy epitaxial thin films. Applied Physics Letters, 2018, 113, .	3.3	7
26	Direct observation of high spin polarization in $\text{Co}_2\text{FeAl}$ thin films. Scientific Reports, 2018, 8, 8074.	3.3	20
27	Emergent Ferromagnetism: Direct Demonstration of the Emergent Magnetism Resulting from the Multivalence Mn in a $\text{LaMnO}_3$ Epitaxial Thin Film System (Adv. Electron. Mater. 6/2018). Advanced Electronic Materials, 2018, 4, 1870030.	5.1	1
28	Unsaturated magnetoconductance of epitaxial $\text{La}_{0.7}\text{Sr}_{0.3}\text{MnO}_3$ thin films in pulsed magnetic fields up to 60 T. AIP Advances, 2017, 7, 056404.	1.3	7
29	Oxygen pressure-tuned epitaxy and magnetic properties of magnetite thin films. Journal of Magnetism and Magnetic Materials, 2017, 432, 472-476.	2.3	15
30	Intrinsic ferromagnetism and quantum transport transition in individual Fe-doped $\text{Bi}_2\text{Se}_3$ topological insulator nanowires. Nanoscale, 2017, 9, 12372-12378.	5.6	18
31	Universal scaling of the anomalous Hall effect. Journal Physics D: Applied Physics, 2017, 50, 155002.	2.8	2
32	Giant Tunability of the Two-Dimensional Electron Gas at the Interface of $\text{Al}_2\text{O}_3/\text{SrTiO}_3$ . Nano Letters, 2017, 17, 6878-6885.	9.1	44
33	Tuning the transport behavior of centimeter-scale $\text{WTe}_2$ ultrathin films fabricated by pulsed laser deposition. Applied Physics Letters, 2017, 111, .	3.3	34
34	Suppressed carrier density for the patterned high mobility two-dimensional electron gas at $\text{Al}_2\text{O}_3/\text{SrTiO}_3$ heterointerfaces. Applied Physics Letters, 2017, 111, 021602.	3.3	18
35	Quantum Electronics: Evidence of Both Surface and Bulk Dirac Bands and Anisotropic Nonsaturating Magnetoresistance in $\text{ZrSiS}$ (Adv. Electron. Mater. 10/2016). Advanced Electronic Materials, 2016, 2, .	5.1	3
36	Room-temperature ferromagnetism observed in Nd-doped $\text{In}_2\text{O}_3$ dilute magnetic semiconducting nanowires. Chinese Physics B, 2016, 25, 097502.	1.4	4

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37	Evidence of Both Surface and Bulk Dirac Bands and Anisotropic Nonsaturating Magnetoresistance in ZrSiS. <i>Advanced Electronic Materials</i> , 2016, 2, 1600228.	5.1	115
38	Evidence of weak localization in quantum interference effects observed in epitaxial La <sub>0.7</sub> Sr <sub>0.3</sub> MnO <sub>3</sub> ultrathin films. <i>Scientific Reports</i> , 2016, 6, 26081.	3.3	61
39	Identification of defect-related emissions in ZnO hybrid materials. <i>Applied Physics Letters</i> , 2015, 107, .	3.3	19
40	Effect of Superparamagnetic Fe <sub>3</sub> O <sub>4</sub> Nanoparticles on Schottky Barriers of Graphene. <i>IEEE Transactions on Magnetics</i> , 2015, 51, 1-4.	2.1	0
41	Fabrication and Characterization of Fe-Doped In <sub>2</sub> O <sub>3</sub> Dilute Magnetic Semiconducting Nanowires. <i>Chinese Physics Letters</i> , 2015, 32, 037501.	3.3	1